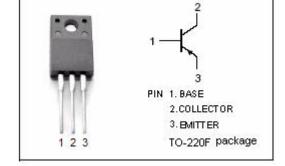


isc Silicon PNP Power Transistor

KTB1366

DESCRIPTION

- · Collector-Emitter Breakdown Voltage-
- : V_{(BR)CEO}= -60V(Min)
- · Collector Power Dissipation-
 - : P_C= 25 W@ T_C= 25 ℃
- · Low Collector Saturation Voltage-
 - : $V_{CE(sat)} = -1.0V(Max)@ (I_C = -2A, I_B = -0.2A)$
- Complement to Type KTD2058
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

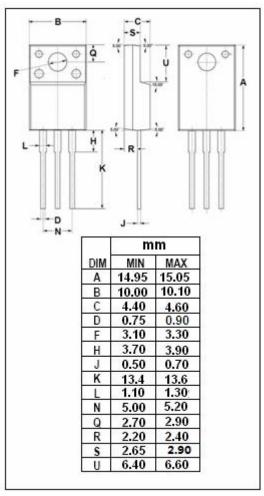


APPLICATIONS

· Designed for general purpose applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V_{CBO}	Collector-Base Voltage	-60	٧	
V _{CEO}	Collector-Emitter Voltage	-60	٧	
V _{EBO}	Emitter-Base Voltage	-7	V	
Ic	Collector Current-Continuous	-3	А	
I _B	Base Current-Continuous	-0.5	Α	
	Collector Power Dissipation @T _a =25°C	2	W	
P _C	Collector Power Dissipation @Tc=25°C	25	VV	
TJ	Junction Temperature	150	$^{\circ}$	
T _{stg}	Storage Temperature	-55~150	$^{\circ}$	





ISC Silicon PNP Power Transistor

KTB1366

ELECTRICAL CHARACTERISTICS

Tj=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _(BR) CEO	Collector-Emitter Breakdown Voltage	I _C = -50mA ; I _B = 0	-60			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -2A; I _B = -0.2A			-1.0	٧
V _{BE(on)}	Base-Emitter On Voltage	I _C = -0.5A; V _{CE} = -5V			-1.0	V
I _{CBO}	Collector Cutoff Current	V _{CB} = -60V; I _E = 0			-100	μА
I _{EBO}	Emitter Cutoff Current	V _{EB} = -7V; I _C = 0			-100	μ А
h _{FE-1}	DC Current Gain	I _C = -0.5A; V _{CE} = -5V	60		200	
h _{FE-2}	DC Current Gain	I _C = -3A; V _{CE} = -5V	20			

♦ h_{FE-1} Classifications

0	Y
60-120	100-200

NOTICE:

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